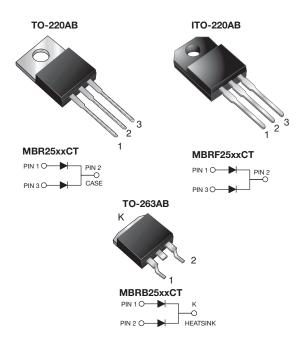
MBR25xxCT, MBRF25xxCT, MBRB25xxCT

Vishay General Semiconductor

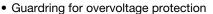
Dual Common Cathode Schottky Rectifier



PRIMARY CHARACTERISTICS							
I _{F(AV)} 2 x 12.5 A							
V _{RRM}	V _{RRM} 35 V to 60 V						
I _{FSM}	150 A						
V _F 0.73 V at 30 A, 0.65 V at 15 A							
T _J max.	150 °C						
Package TO-220AB, ITO-220AB, TO-263AB							
Diode variations	Common cathode						

FEATURES

Power pack



- · Lower power losses, high efficiency
- Low forward voltage drop
- High forward surge capability
- · High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 260 °C, 40 s (for TO-220AB and ITO-220AB package)
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, or polarity protection application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB
Epoxy meets UL 94 V-0 flammability rating
Base P/N-E3 - RoHS-compliant, commercial grade
Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD22-B102

E3 suffix meets JESD 201 class 2 whisker test, HE3 suffix

meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted)							
PARAMETER		SYMBOL	MBR2535CT	MBR2545CT	MBR2550CT	MBR2560CT	UNIT
Maximum repetitive peak reverse voltage		V_{RRM}	35	45	50	60	
Working peak reverse voltage	Working peak reverse voltage		35	45	50	60	V
Maximum DC blocking voltage		V_{DC}	35	45	50	60	1
Maximum average forward rectified current	total device		25				
at T _C = 130 °C	per diode	I _{F(AV)}	12.5				
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I _{FSM}	150				
Peak repetitive reverse surge current per diode at $t_p = 2 \mu s$, 1 kHz		I _{RRM}	1.0 0.5		.5	- A	
Peak non-repetitive reverse energy (8/20 μs waveform) per diode		E _{RSM}	25				mJ
Electrostatic discharge capacitor voltage human body model: C = 100 pF, R = 1.5 k Ω		V _C	25				kV
Voltage rate of change (rated V _R)		dV/dt	10 000			V/µs	
Operating junction temperature range		TJ	-65 to +150			°C	
Storage temperature range		T _{STG}	-65 to +175]
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min		V _{AC}	1500			V	



MBR25xxCT, MBRF25xxCT, MBRB25xxCT

Vishay General Semiconductor

ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	MBR2535CT	MBR2545CT	MBR2550CT	MBR2560CT	UNIT
Maximum instantaneous forward voltage per diode	I _E = 15 A	T _C = 25 °C	C V _F (1)	-		0.75		V
	IF = 13 A	T _C = 125 °C		-		0.65		
	I _F = 30 A	T _C = 25 °C		0.82		-		
	IF = 30 A	T _C = 125 °C		0.73		-		
Maximum instantaneous		T _C = 25 °C			0.2		1.0	
reverse current at blocking voltage per diode		T _C = 125 °C	I _R ⁽¹⁾	4	0	5	0	mA

Note

 $^{^{(1)}\,}$ Pulse test: 300 μs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)						
PARAMETER SYMBOL MBR MBRF MBRB UNIT						
Typical thermal resistance from junction to case per diode	$R_{\theta JC}$	1.5	4.5	1.5	°C/W	

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	MBR2545CT-E3/45	1.85	45	50/tube	Tube		
ITO-220AB	MBRF2545CT-E3/45	1.99	45	50/tube	Tube		
TO-263AB	MBRB2545CT-E3/45	1.35	45	50/tube	Tube		
TO-263AB	MBRB2545CT-E3/81	1.35	81	800/reel	Tape and reel		
TO-220AB	MBR2545CT-E3/4W	1.85	4W	50/tube	Tube		
TO-220AB	MBR2545CTHE3/45 (1)	1.85	45	50/tube	Tube		
ITO-220AB	MBRF2545CTHE3/45 (1)	1.99	45	50/tube	Tube		
TO-263AB	MBRB2545CTHE3/45 (1)	1.35	45	50/tube	Tube		
TO-263AB	MBRB2545CTHE3/81 (1)	1.35	81	800/reel	Tape and reel		

Note

⁽¹⁾ AEC-Q101 qualified

Vishay General Semiconductor

RATINGS AND CHARACTERISTICS CURVES (T_C = 25 °C unless otherwise noted)

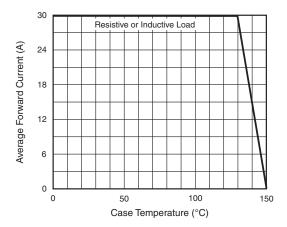


Fig. 1 - Forward Current Derating Curve

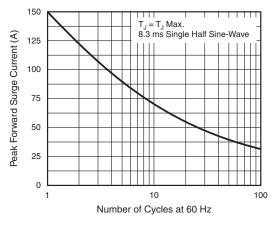


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

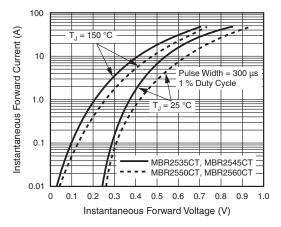


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

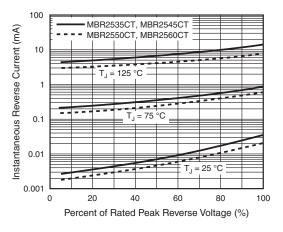


Fig. 4 - Typical Reverse Characteristics Per Diode

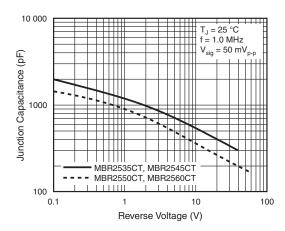


Fig. 5 - Typical Junction Capacitance Per Diode

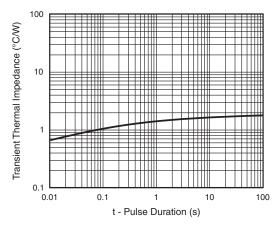


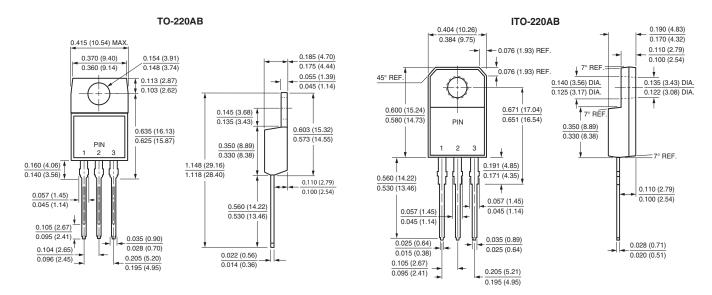
Fig. 6 - Typical Transient Thermal Impedance Per Diode

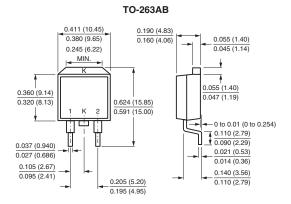


MBR25xxCT, MBRF25xxCT, MBRB25xxCT

Vishay General Semiconductor

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





0.42 (10.66) MIN. 0.33 (8.38) MIN 0.591 (15.00) 0.08 (2.032) MIN. 0.105 (2.67)

0.095 (2.41)

Mounting Pad Layout



Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Material Category Policy

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.

Revision: 02-Oct-12 Document Number: 91000